

MAXIM**2.5Ω, Quad, SPST,
CMOS Analog Switches****General Description**

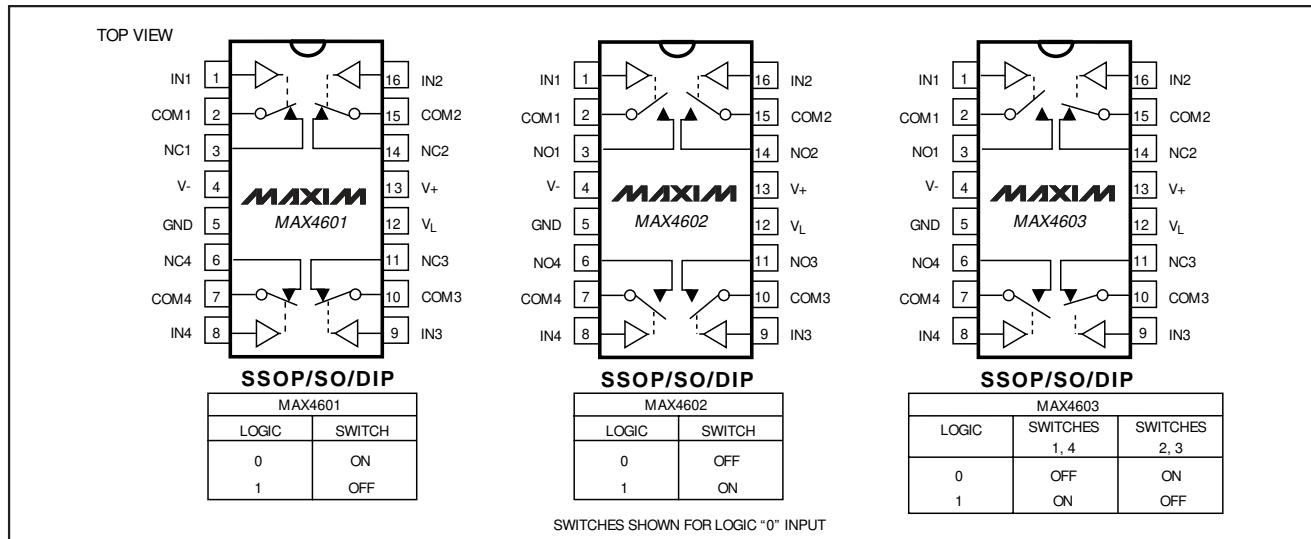
The MAX4601/MAX4602/MAX4603 quad analog switches feature low on-resistance of 2.5Ω max. On-resistance is matched between switches to 0.5Ω max and is flat (0.5Ω max) over the specified signal range. Each switch can handle Rail-to-Rail® analog signals. The off-leakage current is only 2.5nA maximum at TA = +85°C. These analog switches are ideal in low-distortion applications and are the preferred solution over mechanical relays in automatic test equipment or applications where current switching is required. They have low power requirements, require less board space, and are more reliable than mechanical relays.

The MAX4601 has four normally closed (NC) switches, the MAX4602 has four normally open (NO) switches, and the MAX4603 has two NC and two NO switches.

These switches operate from a single supply of +4.5V to +36V or from dual supplies of ±4.5V to ±20V. All digital inputs have +0.8V and +2.4V logic thresholds, ensuring TTL/CMOS-logic compatibility when using ±15V or a single +12V supply.

Applications

- Reed Relay Replacement
- Test Equipment
- Communication Systems
- PBX, PABX Systems
- Audio-Signal Routing
- Avionics

Pin Configurations/Functional Diagrams/Truth Tables

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

MAXIM**Maxim Integrated Products 1**

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MAX4601/MAX4602/MAX4603

2.5Ω, Quad, SPST, CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS

V+ to GND	-0.3V to +44V
V- to GND	+0.3V to -44V
V+ to V-.....	-0.3V to +44V
V _L to GND	(GND - 0.3V) to (V+ + 0.3V)
All Other Pins to DGND (Note 1)	(V- - 0.3V) to (V+ + 0.3V)
Continuous Current (COM __ , NO __ , NC __)	±200mA
Peak Current (COM __ , NO __ , NC __) (pulsed at 1ms, 10% duty cycle)	±300mA

Continuous Power Dissipation (TA = +70°C)	
16 SSOP (derate 7.1mW/°C above +70°C)	571mW
16 Wide SO (derate 9.52mW/°C above +70°C)	762mW
16 Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Operating Temperature Ranges	
MAX460_C_E	0°C to +70°C
MAX460_E_E	-40°C to +85°C
Storage Temperature Range	-65°C to +160°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on NC_{_}, NO_{_}, COM_{_}, or IN_{_} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, V_L = 5V, V_{IN_H} = 2.4V, V_{IN_L} = 0.8V, TA = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at TA = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COM_} , V _{NO_} , V _{NC_}	(Note 3)		V-		V+	V
COM __ to NO or NC __ On-Resistance	R _{ON}	I _{COM} = 10mA, V _{NO_} or V _{NC_} = ±10V	TA = +25°C		1.7	2.5	Ω
			TA = T _{MIN} to T _{MAX}			2.7	
COM __ to NO __ or NC __ On-Resistance Match Between Channels (Note 4)	ΔR _{ON}	I _{COM} = 10mA, V _{NO_} or V _{NC_} = ±10V	TA = +25°C		0.1		Ω
			TA = T _{MIN} to T _{MAX}			0.5	
COM __ to NO __ or NC __ On-Resistance Flatness (Note 5)	R _{FLAT(ON)}	I _{COM} = 10mA; V _{NO_} or V _{NC_} = -5V, 0, 5V	TA = +25°C		0.1	0.4	Ω
			TA = T _{MIN} to T _{MAX}			0.5	
Off-Leakage Current (NO __ or NC __) (Note 6)	I _{NO_} , I _{NC_}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ±10V	TA = +25°C	-0.5	0.01	0.5	nA
			TA = T _{MIN} to T _{MAX}	-2.5		2.5	
COM Off-Leakage Current (Note 6)	I _{COM_(OFF)}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ±10V	TA = +25°C	-0.5	0.01	0.5	nA
			TA = T _{MIN} to T _{MAX}	-2.5		2.5	
COM On-Leakage Current (Note 6)	I _{COM_(ON)}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ±10V or floating	TA = +25°C	-1	0.2	1	nA
			TA = T _{MIN} to T _{MAX}	-10		10	
LOGIC INPUT							
Input Current with Input Voltage High	I _{IN_H}	IN __ = 2.4V, all others = 0.8V		-0.500	0.001	0.500	μA
Input Current with Input Voltage Low	I _{IN_L}	IN __ = 0.8V, all others = 2.4V		-0.500	0.001	0.500	μA
Logic Input High Voltage	V _{IN_H}			2.4	1.7		V
Logic Input Low Voltage	V _{IN_L}				1.7	0.8	V

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

($V_+ = +15V$, $V_- = -15V$, $V_L = 5V$, $V_{IN_H} = 2.4V$, $V_{IN_L} = 0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
Power-Supply Range			± 4.5	± 20.0		V
Positive Supply Current	I_+	All channels on or off, $V_{IN} = 0$ or $5V$	$T_A = +25^\circ C$	-0.5	0.001	0.5
			$T_A = T_{MIN}$ to T_{MAX}	-5		5
Negative Supply Current	I_-	All channels on or off, $V_{IN} = 0$ or $5V$	$T_A = +25^\circ C$	-0.5	0.001	0.5
			$T_A = T_{MIN}$ to T_{MAX}	-5		5
Logic Supply Current	I_L	All channels on or off, $V_{IN} = 0$ or $5V$	$T_A = +25^\circ C$	-0.5	0.001	0.5
			$T_A = T_{MIN}$ to T_{MAX}	-5		5
Ground Current	I_{GND}	All channels on or off, $V_{IN} = 0$ or $5V$	$T_A = +25^\circ C$	-0.5	0.001	0.5
			$T_A = T_{MIN}$ to T_{MAX}	-5		5
SWITCH DYNAMIC CHARACTERISTICS						
Turn-On Time	t_{ON}	Figure 2, $V_{COM_} = \pm 10V$, $T_A = +25^\circ C$	160	250		ns
Turn-Off Time	t_{OFF}	Figure 2, $V_{COM_} = \pm 10V$, $T_A = +25^\circ C$	190	350		ns
Charge Injection	Q	$C_L = 1.0nF$, $V_{GEN} = 0$, $R_{GEN} = 0$, Figure 3, $T_A = +25^\circ C$	120			pC
Off-Isolation (Note 7)	V_{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4, $T_A = +25^\circ C$	-56			dB
Crosstalk (Note 8)	V_{CT}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 5, $T_A = +25^\circ C$	-59			dB
NC_ or NO_ Capacitance	$C_{(OFF)}$	$f = 1MHz$, Figure 6, $T_A = +25^\circ C$	55			pF
COM Off-Capacitance	$C_{(COM)}$	$f = 1MHz$, Figure 6, $T_A = +25^\circ C$	55			pF
On-Capacitance	$C_{(COM)}$	$f = 1MHz$, Figure 7, $T_A = +25^\circ C$	250			pF

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ELECTRICAL CHARACTERISTICS—Single +12V Supply

($V_+ = 12V$, $V_- = 0$, $V_L = 5V$, $V_{IN_H} = 2.4V$, $V_{IN_L} = 0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ C$.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	$V_{COM_}$, $V_{NO_}$, $V_{NC_}$	(Note 3)		GND		V_+	V
COM_to NO or NC On-Resistance	R_{ON}	$I_{COM_} = 10mA$, $V_{NO_}$ or $V_{NC_} = 10V$		$T_A = +25^\circ C$	3	4	Ω
		$T_A = T_{MIN}$ to T_{MAX}				5	
COM_to NO or NC On-Resistance Match Between Channels (Note 4)	ΔR_{ON}	$I_{COM_} = 10mA$, $V_{NO_}$ or $V_{NC_} = 10V$		$T_A = +25^\circ C$	0.03	0.4	Ω
		$T_A = T_{MIN}$ to T_{MAX}				0.5	
COM_to NO or NC On-Resistance Flatness (Note 5)	$R_{FLAT(ON)}$	$I_{COM_} = 10mA$; $V_{NO_}$ or $V_{NC_} = 3V$, 6V, 9V		$T_A = +25^\circ C$	0.1	0.4	Ω
		$T_A = T_{MIN}$ to T_{MAX}				0.5	
Off-Leakage Current (NO or NC) (Notes 6, 9)	$I_{NO_}$ $I_{NC_}$	$V_{COM_} = 1V$, 10V; $V_{NO_}$ or $V_{NC_} = 10V$, 1V		$T_A = +25^\circ C$	-0.5	0.01	nA
		$T_A = T_{MIN}$ to T_{MAX}			-2.5	2.5	
COM Off-Leakage Current (Notes 6, 9)	I_{COM_OFF}	$V_{NO_}$ or $V_{NC_} = 10V$, 1V; $V_{COM_} = 1V$, 10V		$T_A = +25^\circ C$	-0.5	0.01	nA
		$T_A = T_{MIN}$ to T_{MAX}			-2.5	2.5	
COM On-Leakage Current (Notes 6, 9)	I_{COM_ON}	$V_{COM_} = 1V$, 10V; $V_{NO_}$ or $V_{NC_} = 1V$, 10V, or floating		$T_A = +25^\circ C$	-1	0.01	nA
		$T_A = T_{MIN}$ to T_{MAX}			-10	10	
LOGIC INPUT							
Input Current with Input Voltage High	I_{IN_H}	$IN_ = 2.4V$, all others = 0.8V		-0.500	0.001	0.500	μA
Input Current with Input Voltage Low	I_{IN_L}	$IN_ = 0.8V$, all others = 2.4V		-0.500	0.001	0.500	μA
Logic Input High Voltage	V_{IN_H}				2.4		V
Logic Input Low Voltage	V_{IN_L}					0.8	V
POWER SUPPLY							
Power-Supply Range				4.5		36.0	V
Positive Supply Current	I_+	All channels on or off, $V_{IN} = 0$ or 5V		$T_A = +25^\circ C$	-0.5	0.001	μA
		$T_A = T_{MIN}$ to T_{MAX}			-5	5	
Logic Supply Current	I_L	All channels on or off, $V_{IN} = 0$ or 5V		$T_A = +25^\circ C$	-0.5	0.001	μA
		$T_A = T_{MIN}$ to T_{MAX}			-5	5	
Ground Current	I_{GND}	$V_{IN} = 0$ or 5V		$T_A = +25^\circ C$	-0.5	0.001	μA
		$T_A = T_{MIN}$ to T_{MAX}			-5	5	

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ELECTRICAL CHARACTERISTICS—Single +12V Supply (continued)

($V_+ = 12V$, $V_- = 0$, $V_L = 5V$, $V_{IN_H} = 2.4V$, $V_{IN_L} = 0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN (Note 2)	TYP	MAX	UNITS
SWITCH DYNAMIC CHARACTERISTICS						
Turn-On Time	t_{ON}	Figure 2, $V_{COM_} = 10V$, $T_A = +25^\circ C$	160			ns
Turn-Off Time	t_{OFF}	Figure 2, $V_{COM_} = 10V$, $T_A = +25^\circ C$	170			ns
Charge Injection	Q	$C_L = 1.0nF$, $V_{GEN} = 0$, $R_{GEN} = 0$, Figure 3, $T_A = +25^\circ C$	20			pC
Crosstalk (Note 8)	V_{CT}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 5, $T_A = +25^\circ C$	-60			dB
NC_ or NO_ Capacitance	$C_{(OFF)}$	$f = 1MHz$, Figure 6, $T_A = +25^\circ C$	85			pF
COM Off-Capacitance	$C_{(COM)}$	$f = 1MHz$, Figure 6, $T_A = +25^\circ C$	85			pF
On-Capacitance	$C_{(COM)}$	$f = 1MHz$, Figure 7, $T_A = +25^\circ C$	140			pF

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at $+25^\circ C$.

Note 7: Off-isolation = $20 \log_{10} [V_{COM} / (V_{NC} \text{ or } V_{NO})]$, V_{COM} = output, V_{NC} or V_{NO} = input to off switch.

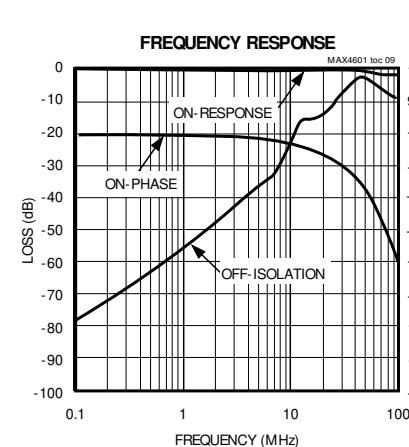
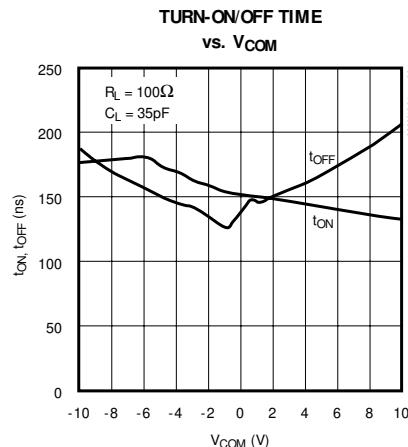
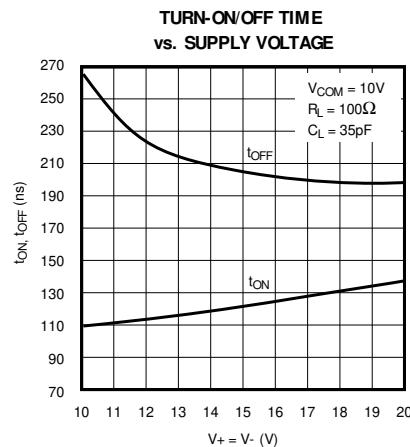
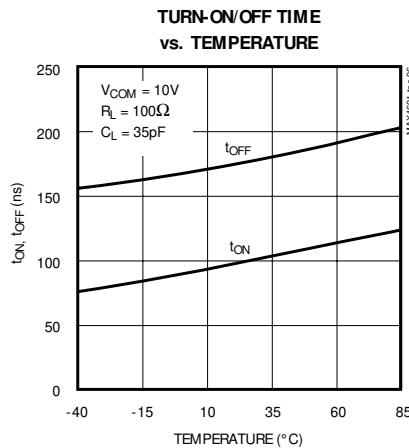
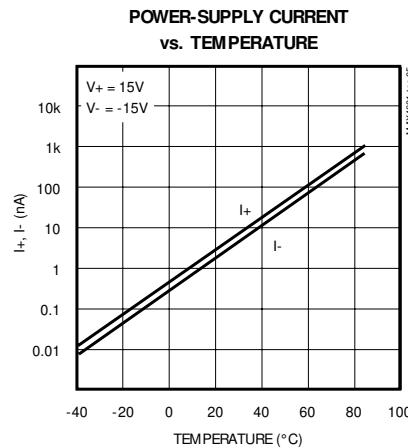
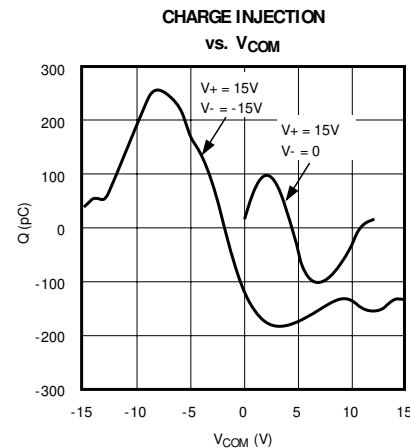
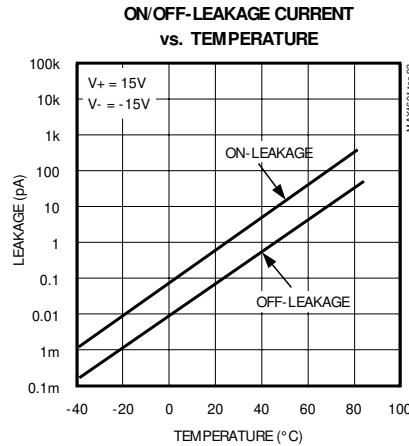
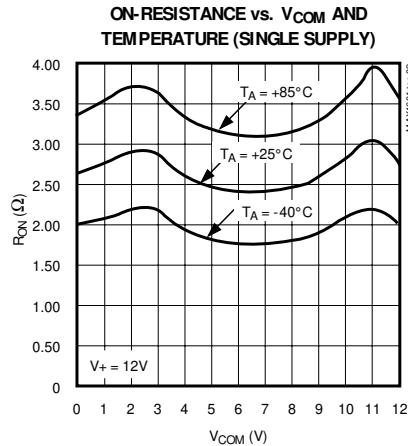
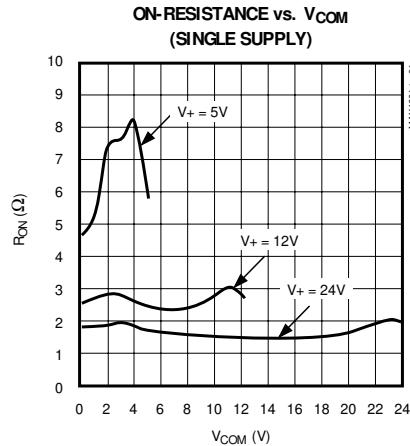
Note 8: Between any two switches.

Note 9: Leakage testing at single supply is guaranteed by testing with dual supplies.

2.5Ω, Quad, SPST, CMOS Analog Switches

Typical Operating Characteristics

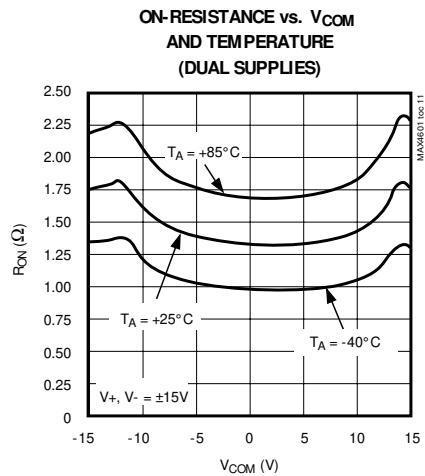
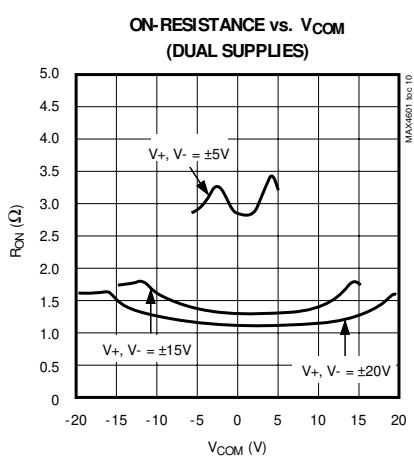
(TA = +25°C, unless otherwise noted.)



2.5Ω, Quad, SPST, CMOS Analog Switches

Typical Operating Characteristics (continued)

($T_A = +25^\circ\text{C}$, unless otherwise noted.)



Pin Description

PIN			NAME	FUNCTION
MAX4601	MAX4602	MAX4603		
1, 16, 9, 8	1, 16, 9, 8	1, 16, 9, 8	IN1, IN2, IN3, IN4	Logic-Control Digital Inputs
2, 15, 10, 7	2, 15, 10, 7	2, 15, 10, 7	COM1, COM2, COM3, COM4	Analog Switch Common Terminals
3, 14, 11, 6	—	—	NC1, NC2, NC3, NC4	Analog Switch Normally Closed Terminals
—	3, 14, 11, 6	—	NO1, NO2, NO3, NO4	Analog Switch Normally Open Terminals
—	—	3, 6	NO1, NO4	Analog Switch Normally Open Terminals
—	—	14, 11	NC2, NC3	Analog Switch Normally Closed Terminals
4	4	4	V-	Negative Analog Supply-Voltage Input. Connect to GND for single-supply operation.
5	5	5	GND	Ground
12	12	12	V _L	Logic-Supply Input
13	13	13	V ₊	Positive Analog Supply Input

2.5Ω, Quad, SPST, CMOS Analog Switches

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V₊ on first, then V₋, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V₊ and one diode drop above V₋, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V₊ and V₋ should not exceed 44V. These protection diodes are not recommended when using a single supply.

Off-Isolation at High Frequencies

In 50Ω systems, the high-frequency on-response of these parts extends from DC to above 100MHz with a typical loss of -2dB. When the switch is turned off, however, it behaves like a capacitor, and off-isolation decreases with increasing frequency. (Above 300MHz, the switch actually passes more signal turned off than turned on.) This effect is more pronounced with higher source and load impedances.

Above 5MHz, circuit board layout becomes critical, and it becomes difficult to characterize the response of the

switch independent of the circuit. The graphs shown in the *Typical Operating Characteristics* were taken using a 50Ω source and load connected with BNC connectors to a circuit board deemed "average;" that is, designed with isolation in mind, but not using strip-line or other special RF circuit techniques. For critical applications above 5MHz, use the MAX440, MAX441, and MAX442, which are fully characterized up to 160MHz.

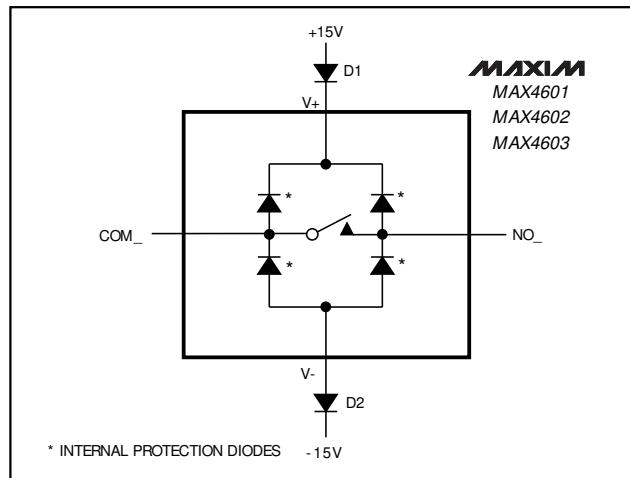


Figure 1. Overvoltage Protection Using External Blocking Diodes

Timing Diagrams/Test Circuits

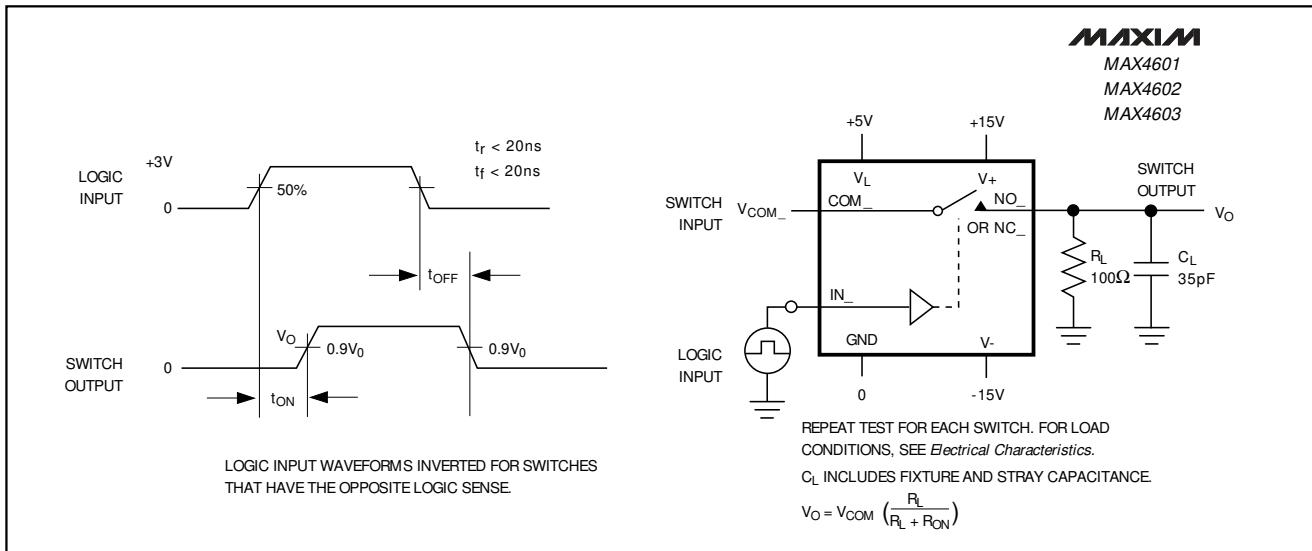


Figure 2. Switching-Time Test Circuit

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Timing Diagrams/Test Circuits (continued)

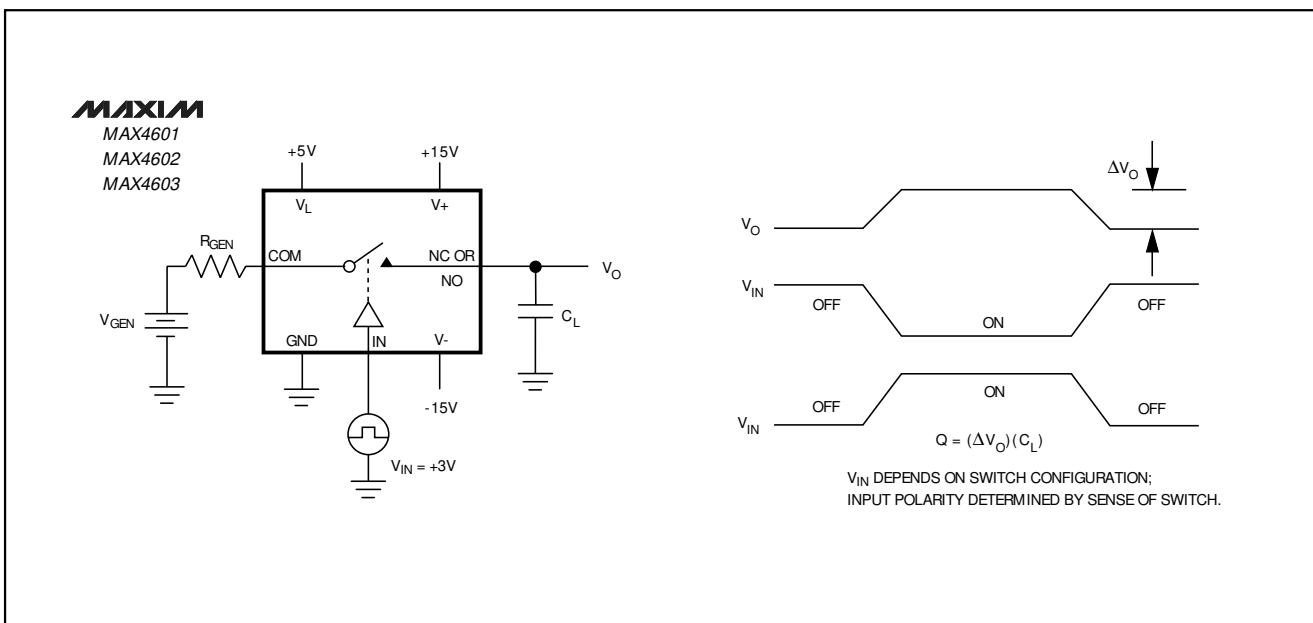


Figure 3. Charge-Injection Test Circuit

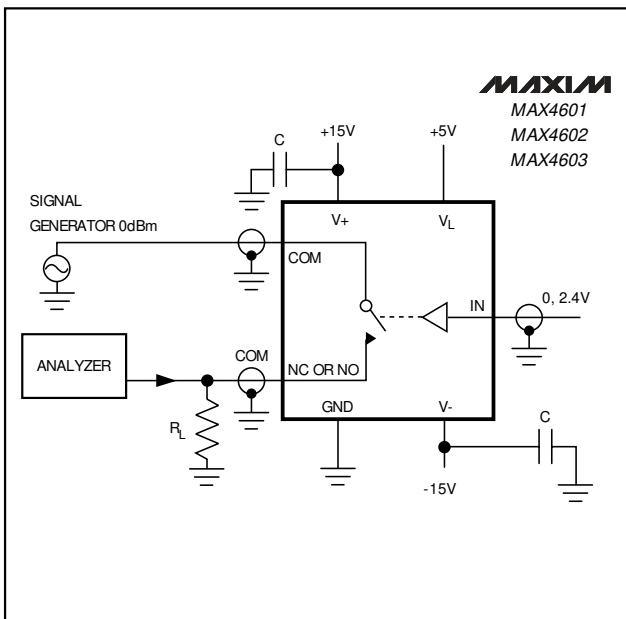


Figure 4. Off-Isolation Test Circuit

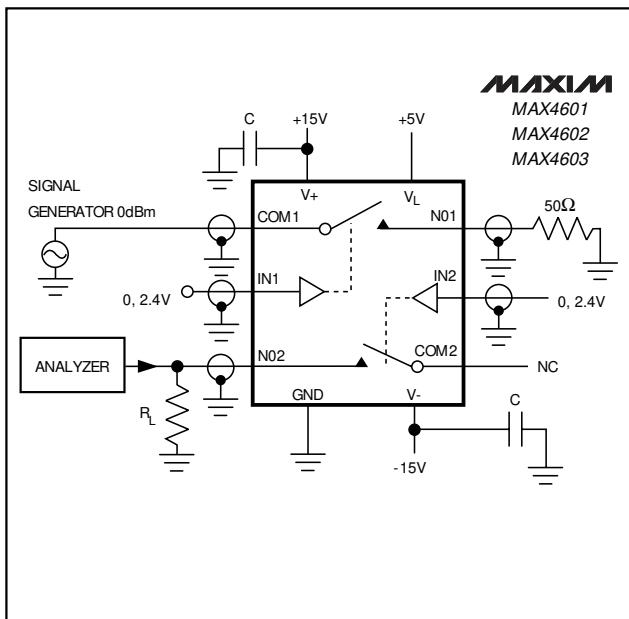


Figure 5. Crosstalk Test Circuit

2.5Ω, Quad, SPST, CMOS Analog Switches

Timing Diagrams/Test Circuits (continued)

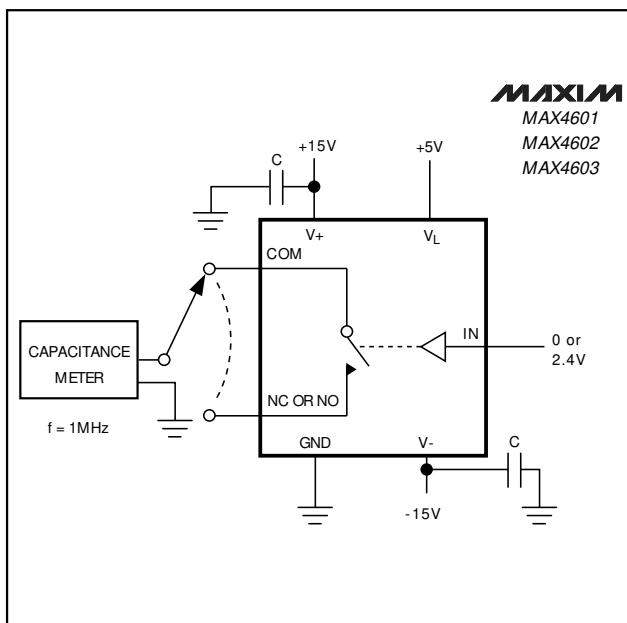


Figure 6. Switch Off-Capacitance Test Circuit

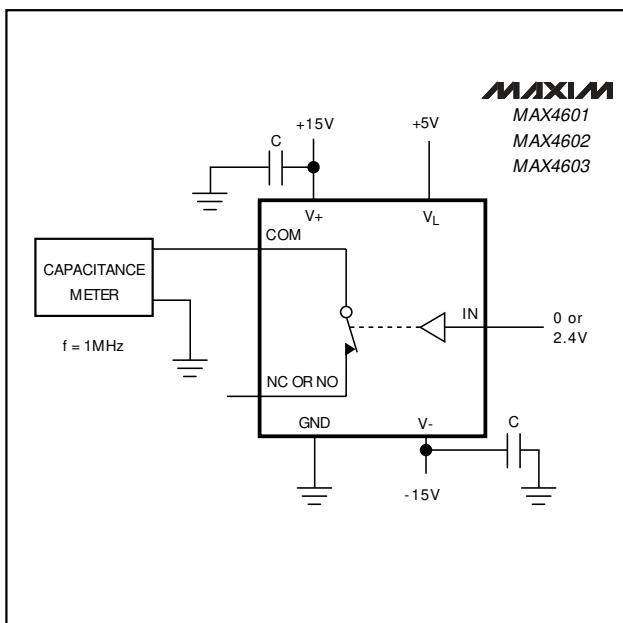


Figure 7. Switch On-Capacitance Test Circuit

Ordering Information (continued)

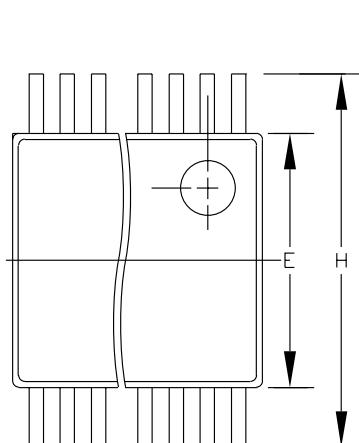
PART	TEMP. RANGE	PIN-PACKAGE
MAX4602CAE	0°C to +70°C	16 SSOP
MAX4602CWE	0°C to +70°C	16 Wide SO
MAX4602CPE	0°C to +70°C	16 Plastic DIP
MAX4602EAE	-40°C to +85°C	16 SSOP
MAX4602EWE	-40°C to +85°C	16 Wide SO
MAX4602EPE	-40°C to +85°C	16 Plastic DIP
MAX4603CAE	0°C to +70°C	16 SSOP
MAX4603CWE	0°C to +70°C	16 Wide SO
MAX4603CPE	0°C to +70°C	16 Plastic DIP
MAX4603EAE	-40°C to +85°C	16 SSOP
MAX4603EWE	-40°C to +85°C	16 Wide SO
MAX4603EPE	-40°C to +85°C	16 Plastic DIP

Chip Information

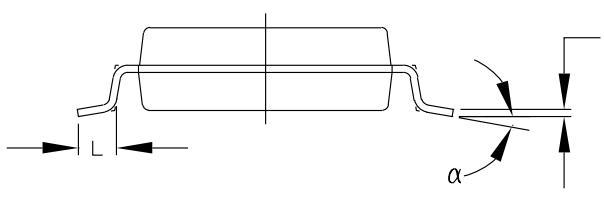
TRANSISTOR COUNT: 100

2.5Ω, Quad, SPST, CMOS Analog Switches

Package Information



INCHES			MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.068	0.078	1.73	1.99
A1	0.002	0.008	0.05	0.21
B	0.010	0.015	0.25	0.38
C	0.004	0.008	0.09	0.20
D	SEE VARIATIONS			
E	0.205	0.209	5.20	5.38
e	0.0256	BSC	0.65	BSC
H	0.301	0.311	7.65	7.90
L	0.025	0.037	0.63	0.95
α	0°	8°	0°	8°



INCHES			MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
D	0.239	0.249	6.07	6.33
D	0.239	0.249	6.07	6.33
D	0.278	0.289	7.07	7.33
D	0.317	0.328	8.07	8.33
D	0.397	0.407	10.07	10.33

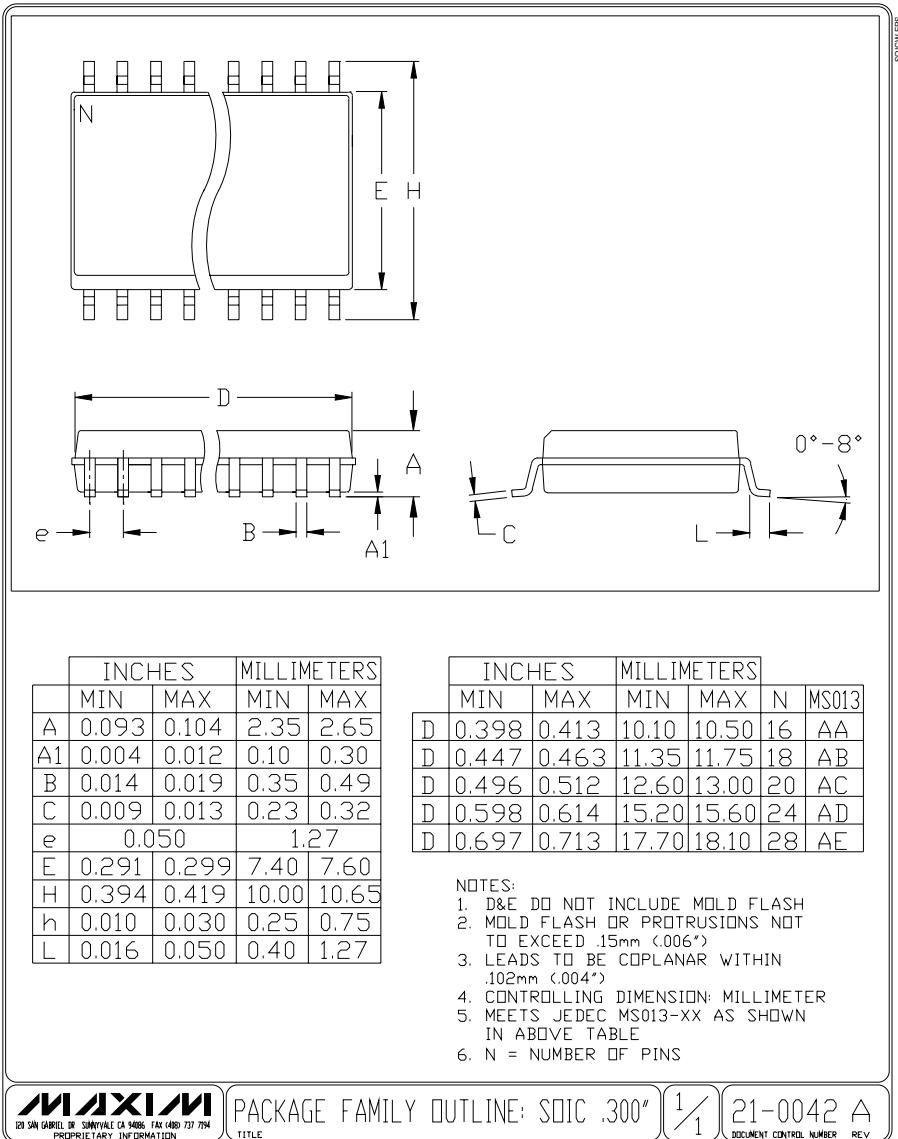
MAXIM	
PROPRIETARY INFORMATION	
TITLE: PACKAGE OUTLINE, SSOP, 5.3X.65MM	
APPROVAL	DOCUMENT CONTROL NO.
21-0056	
REV	1/1
A	

NOTES:

1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED .15mm (.006")
3. CONTROLLING DIMENSION: MILLIMETER

2.5Ω, Quad, SPST, CMOS Analog Switches

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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